



NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK



MICROWAVE CORPORATION v00.0911



HMC1019LP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Typical Applications

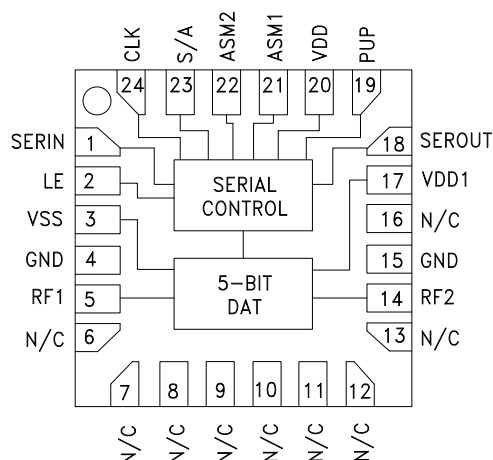
The HMC1019LP4E is ideal for:

- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Space Applications
- Sensors
- Test & Measurement Equipment

Features

- 0.5 dB LSB Steps to 15.5 dB
- TTL/CMOS Compatible, Serial Control
- Unique Asynchronous Mode Control Allows Immediate Attenuation Level Setting
- ±0.5 dB Typical Bit Error
- High Input IP3: +45 dBm
- 24 Lead 4x4mm SMT Package: 16mm²

Functional Diagram



General Description

The HMC1019LP4E is a broadband 5-bit GaAs IC digital attenuator in a low cost leadless surface mount package. Covering 0.1 to 30.0 GHz, the insertion loss is less than 4.0 dB typical. The attenuator bit values are 0.5 (LSB), 1, 2, 4, 8 for a total attenuation of 15.5 dB. Attenuation accuracy is excellent at ±0.3 dB typical step error with an IIP3 of +45 dBm. The control interface is CMOS/TTL compatible and accepts a three wire serial input. The HMC1019LP4E features a user selectable power up state and a serial-output port for cascading other Hittite serial controlled components.

Electrical Specifications, $T_A = +25^\circ \text{C}$, With $V_{dd} = V_{dd1} = +5\text{V}$, $V_{ss} = -5\text{V}$

Parameter	Frequency (GHz)	Min.	Typ.	Max.	Units
Insertion Loss	0.1 - 18.0 GHz		3.0	4.5	dB
	18.0 - 26.5 GHz		4.0	6.0	dB
	26.5 - 30.0 GHz		5.0	6.5	dB
Attenuation Range	0.1 - 30.0 GHz		31		dB
Return Loss (RF1 & RF2, All Atten. States)	0.1 - 30.0 GHz		12		dB
Attenuation Accuracy: (Referenced to Insertion Loss)	0.5 - 7.5 dB States	± (0.3 + 6%) of Atten. Setting Max			dB
	8 - 15.5 dB States	± (0.3 + 8%) of Atten. Setting Max			dB
Input Power for 0.1 dB Compression	0.1 - 0.5 GHz		22		dBm
	0.5 - 30.0 GHz		27		dBm
Input Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)	0.1 - 0.5 GHz		42		dBm
	0.5 - 30.0 GHz		45		dBm
Switching Characteristics	0.1 - 30.0 GHz	tRISE, tFALL (10/90% RF)	60		ns
		tON/tOFF (50% CTL to 10/90% RF)	90		ns
I _{dd1}	0.1 - 30.0 GHz	2.5	4.5	6.5	mA
I _{ss}	0.1 - 30.0 GHz	-7.0	-5.0	-3.0	mA

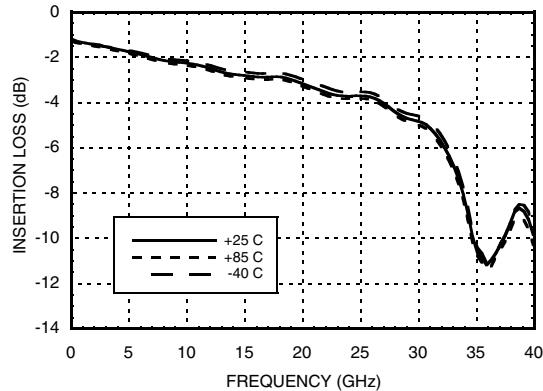
For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

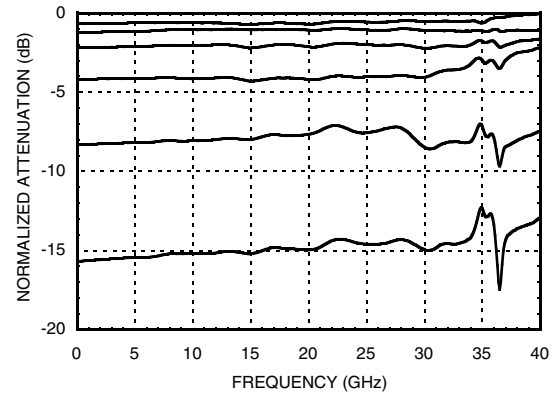
0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Insertion Loss vs. Temperature



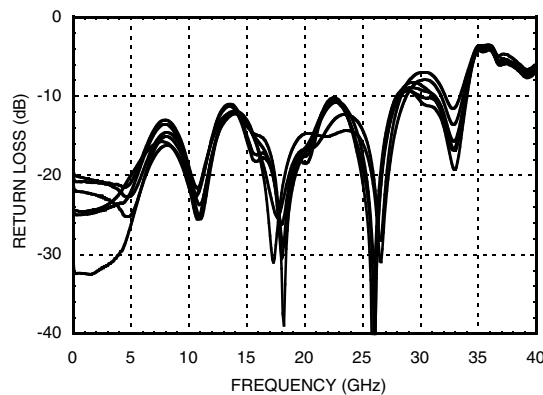
Normalized Attenuation

(Only Major States are Shown)



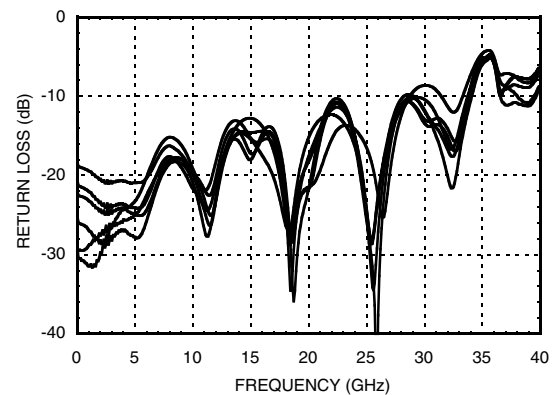
Input Return Loss

(Only Major States are Shown)

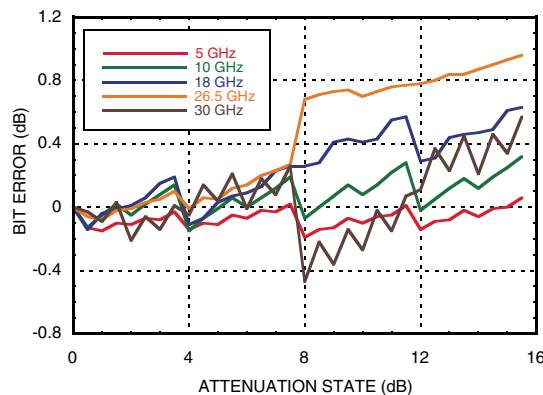


Output Return Loss

(Only Major States are Shown)

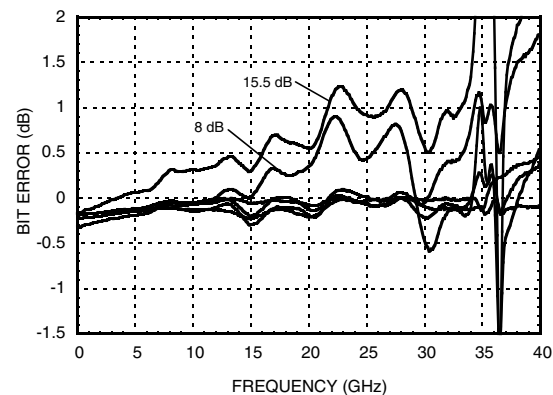


Bit Error vs. Attenuation State



Bit Error vs. Frequency

(Only Major States are Shown)

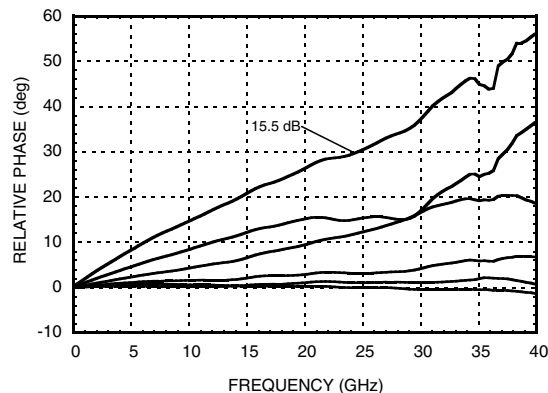




MICROWAVE CORPORATION v00.0911



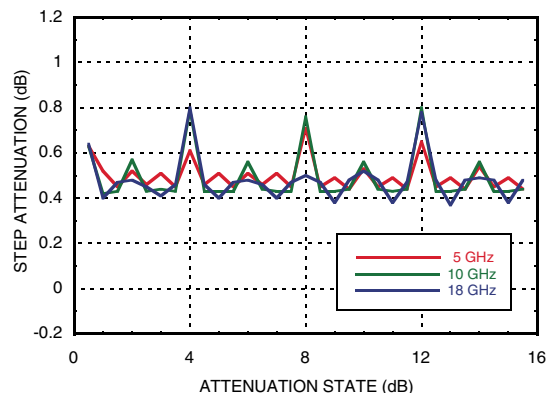
Relative Phase vs. Frequency (Only Major States are Shown)



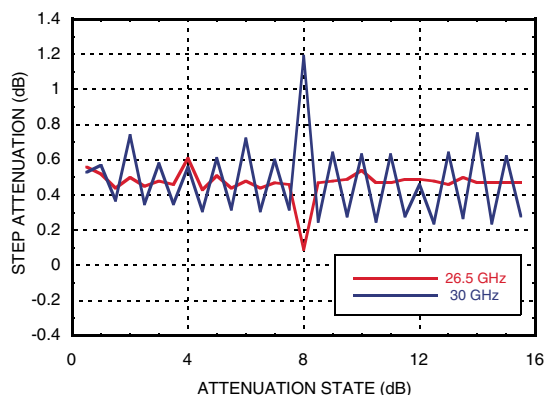
HMC1019LP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

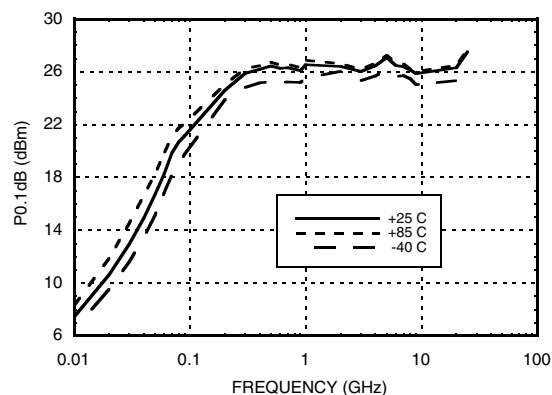
Step Attenuation vs. Attenuation State 0.1 - 18 GHz



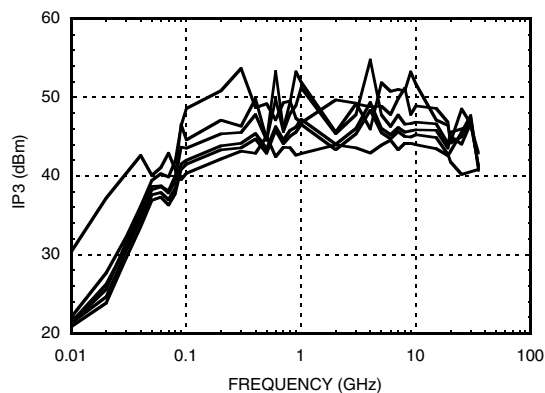
Step Attenuation vs. Attenuation State 18 - 30 GHz



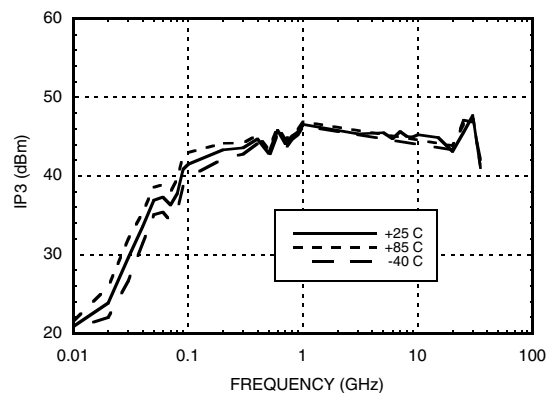
Input Power for 0.1 dB Compression



Input IP3 Over Major Attenuation States



Input IP3 vs. Temperature (Minimum Attenuation State)

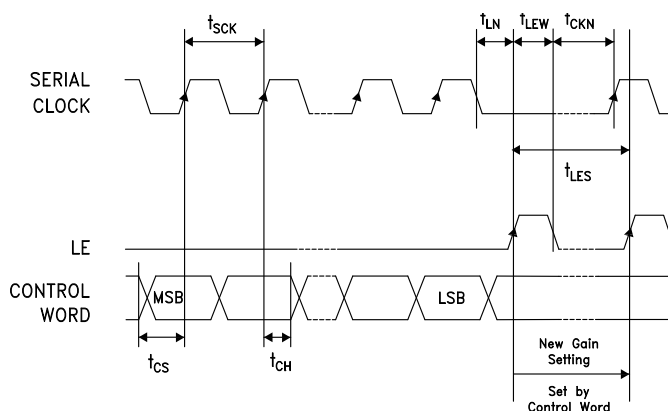


0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Serial Control Interface

The HMC1019LP4E contains a 3-wire SPI compatible digital interface (SERIN, CLK, LE). The serial control interface is activated when S/A is kept high. The 5-bit serial word must be loaded MSB first as a 6-bit word with the first bit ignored. The positive-edge sensitive CLK and LE requires clean transitions. If mechanical switches are used, sufficient debouncing should be provided. When LE is high, 5-bit data in the serial input register is transferred to the attenuator. When LE is high CLK is masked to prevent data transition during output loading.

For all modes of operations, the state will stay constant while LE is kept low.



Serial Mode Truth Table

Control Voltage Input					Attenuation State RF1 - RF2
P4 8 dB	P3 4 dB	P2 2 dB	P1 1 dB	P0 0.5 dB	
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	0.5 dB
High	High	High	Low	High	1 dB
High	High	Low	High	High	2 dB
High	Low	High	High	High	4 dB
Low	High	High	High	High	8 dB
Low	Low	Low	Low	Low	15.5 dB

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Parameter	Typ.
Min. serial period, t_{SCK}	100 ns
Control set-up time, t_{CS}	20 ns
Control hold-time, t_{CH}	20 ns
LE setup-time, t_{LN}	10 ns
Min. LE pulse width, t_{LEW}	10 ns
Min LE pulse spacing, t_{LES}	630 ns
Serial clock hold-time from LE, t_{CKN}	10 ns
Hold Time, t_{PH}	0 ns
Latch Enable Minimum Width, t_{LEN}	10 ns
Setup Time, t_{PS}	2 ns

Asynchronous Mode

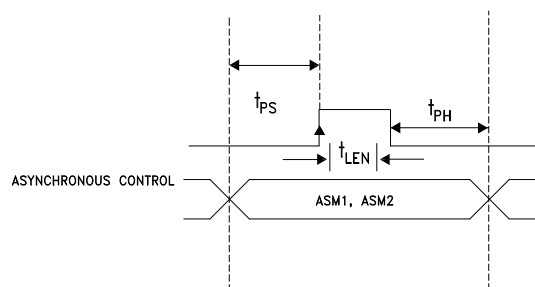
The HMC1019LP4E can be switched to an asynchronous mode to change the attenuation state rapidly to one of four predefined states. The logic state of ASM1-ASM2 determines one of the four attenuation states in the asynchronous mode per truth table. The asynchronous mode works either directly or latched. To activate the direct-asynchronous-mode, S/A needs to be at logic low and LE needs to be at logic high. In the direct-asynchronous-mode, any change in the logic state of ASM1-ASM2 directly affects the attenuation state. In the latched-asynchronous-mode, the attenuation state changes per the asynchronous mode truth table when S/A is at logic low and LE is pulsed per the timing diagram. The attenuation stays constant (latched) as long as LE stays low. In the asynchronous mode, the inputs SERIN and CLK do not affect the attenuation state.



MICROWAVE CORPORATION v00.0911



Timing Diagram (Latched Asynchronous Mode)



Power-Up States

If LE is set to logic LOW at power-up, the logic state of PUP determines the power-up state of the part per PUP truth table. If the LE is set to logic HIGH at power-up, the logic state of ASM1-ASM2 determines the power-up state of the part per truth table for the asynchronous mode. The attenuator latches in the desired power-up state approximately 200 ms after power-up.

Bias Voltages & Currents

Vdd	+5V @ 0.2 mA
Vdd1	+5V @ 4.5 mA
Vss	-5V @ 5 mA

HMC1019LP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Asynchronous Mode Truth Table

ASM1	ASM2	Attenuation State RF1-RF2
High	High	Reference I.L.
High	Low	1.5 dB
Low	High	14 dB
Low	Low	15.5 dB

PUP Truth Table

PUP	Attenuation State
High	Reference I.L.
Low	15.5 dB

Note: The logic state of ASM1-ASM2 determines the power-up state of the part per truth table for the asynchronous mode when LE is high at power-up.

Control Voltage

State	Bias Condition
Low	0 to 0.8V @ 1 μ A
High	2 to 5V @ 1 μ A



Absolute Maximum Ratings

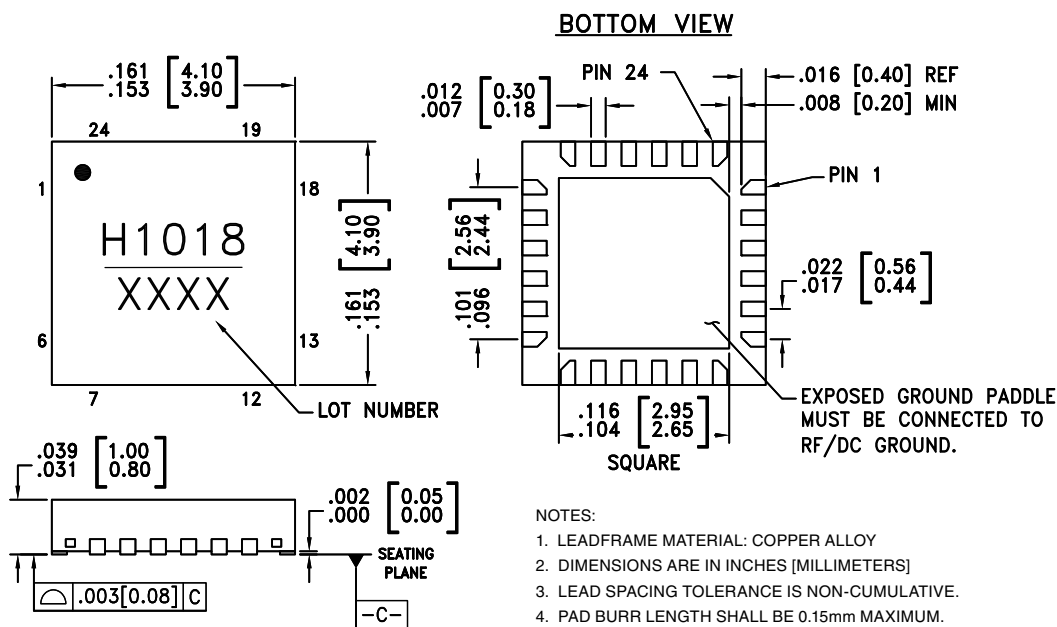
RF Input Power (0.1 to 30.0 GHz)	+27 dBm
Control Voltage (CLK, SERIN, LE, PUP, ASM1, ASM2, S/A)	Vdd + 0.5V
Vdd, Vdd1	+7 Vdc
Vss	-7 Vdc
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 6.8 mW/°C above 85 °C)	0.445 W
Thermal Resistance	146 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE
SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED
LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC1019LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[1]	H1019 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



MICROWAVE CORPORATION

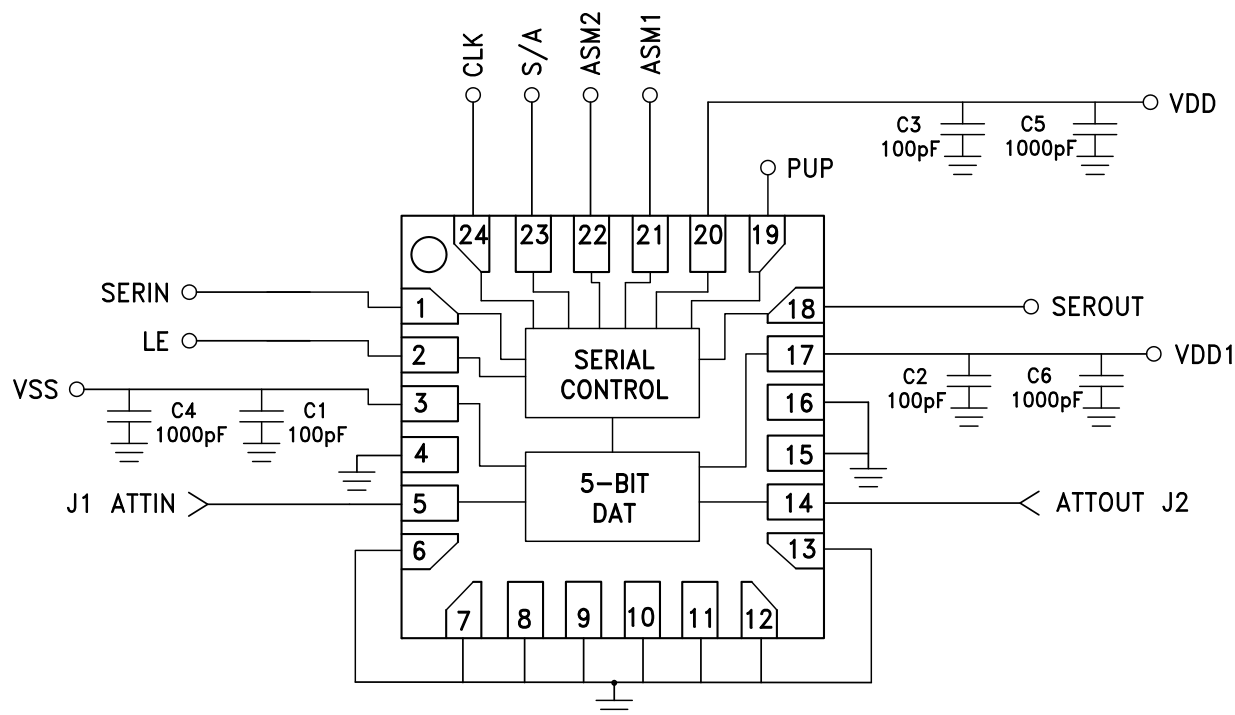
v00.0911

**HMC1019LP4E****0.5 dB LSB GaAs MMIC 5-BIT DIGITAL
ATTENUATOR, 0.1 - 30 GHz****Pin Descriptions**

Pad Number	Function	Description	Interface Schematic
1 2	SERIN LE	See truth table, control voltage table and timing diagram.	
3	Vss	Negative Bias -5V	
4, 15	GND	These pins and package bottom must be connected to RF/DC ground.	
6-13, 16	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
5, 14	RF1, RF2	These pins are DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
17	Vdd1	Positive Bias +5V	
18	SEROUT	Serial input data delayed by 6 clock cycles.	
19 21 22 23 24	PUP ASM1 ASM2 S/A CLK	See truth table, control voltage table and timing diagram.	
20	Vdd	Serial Controller Bias +5V	

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Application Circuit





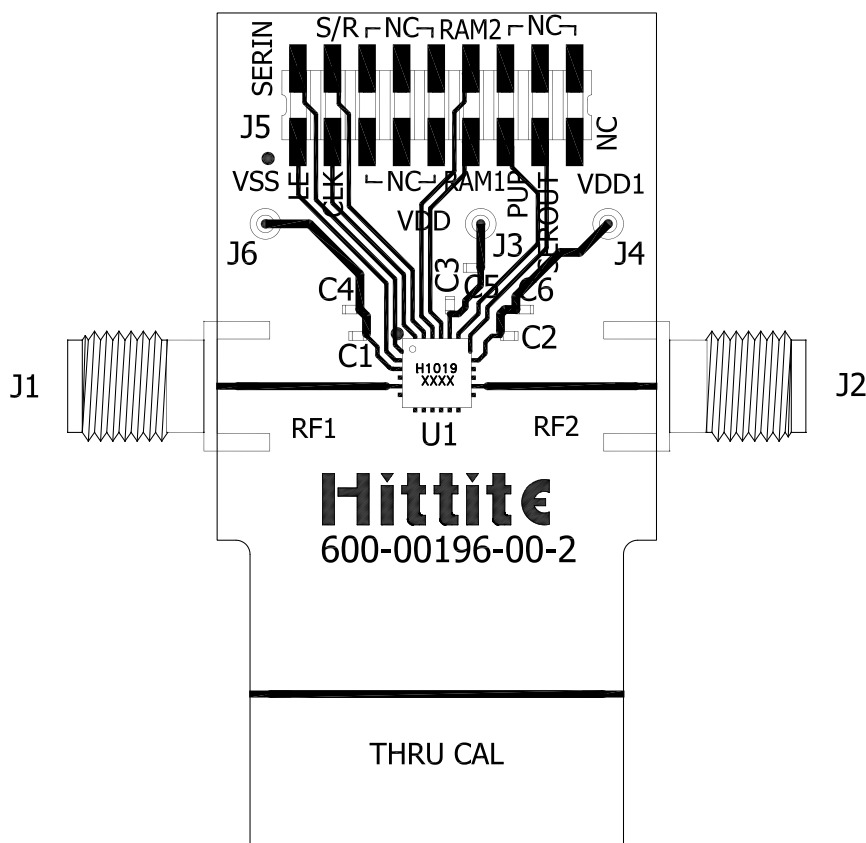
MICROWAVE CORPORATION v00.0911



Evaluation PCB

HMC1019LP4E

0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz



List of Materials for Evaluation PCB EVAL01-HMC1019LP4E ^[1]

Item	Description
J1, J2	2.9 mm PC Mount RF Connector
J3, J4, J6	DC Connector
J5	2mm DC Header
C1-C3	100 pF Capacitor, 0402 Pkg.
C4-C6	1000 pF Capacitor, 0402 Pkg.
U1	HMC1019LP4E Digital Attenuator
PCB ^[2]	600-00196-00-2 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 30 GHz

Notes:



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.